#### **Phonons**

#### at low temperatures

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# Outline

- 1. Microscopic description of crystal vibrations, phonon band structure, experimental probes
- 2. Phonon kinetics in insulators
- 3. Electron-phonon coupling and phonon kinetics in metals
- 4. Relaxation cascade in a detector



**Step 1**: Find the electron ground state at fixed positions of the nuclei  $\{\mathbf{R}_n\}$ 

$$\hat{H}_{el}(\{\mathbf{R}_n\}) = -\sum_i \frac{\hbar^2}{2m} \frac{\partial^2}{\partial \mathbf{r}_i^2} + \sum_{i < j} \frac{e^2}{|\mathbf{r}_i - \mathbf{r}_j|} - \sum_{i,n} \frac{Z_n e^2}{|\mathbf{r}_i - \mathbf{R}_n|}$$
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 $\hat{H}_{\rm el}(\{\mathbf{R}_n\})\,\Psi(\{\mathbf{r}_i\}|\{\mathbf{R}_n\}) = E_0(\{\mathbf{R}_n\})\,\Psi(\{\mathbf{r}_i\}|\{\mathbf{R}_n\})$ 

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$$\hat{H}_{el}(\{\mathbf{R}_n\}) \Psi(\{\mathbf{r}_i\} | \{\mathbf{R}_n\}) = E_0(\{\mathbf{R}_n\}) \Psi(\{\mathbf{r}_i\} | \{\mathbf{R}_n\})$$

**Step 2**: Use the obtained electron ground state energy  $E_0({\mathbf{R}_n})$  as an additional potential energy of the nuclei:

$$\hat{H}_{\rm N} = -\sum_{n} \frac{\hbar^2}{2M_n} \frac{\partial^2}{\partial \mathbf{R}_n^2} + \sum_{n < n'} \frac{Z_n Z_{n'} e^2}{|\mathbf{R}_n - \mathbf{R}_{n'}|} + E_0(\{\mathbf{R}_n\})$$

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**Step 2**: Use the obtained electron ground state energy  $E_0({\mathbf{R}_n})$  as an additional potential energy of the nuclei:

$$\hat{H}_{N} = -\sum_{n} \frac{\hbar^{2}}{2M_{n}} \frac{2^{2}}{2R_{n}^{2}} + \sum_{n < n'} \frac{Z_{n}Z_{n'}e^{2}}{|\mathbf{R}_{n} - \mathbf{R}_{n'}|} + E_{0}(\{\mathbf{R}_{n}\})$$

$$W(\{\mathbf{R}_{n}\})$$

$$\mathbb{I}$$
minimize with respect to  $\{\mathbf{R}_{n}\}$ 
equilibrium atomic positions



Crystal:  $N \to \infty$  unit cells,  $\nu$  atoms per unit cell Equilibrium atomic positions:  $\mathbf{R}_{n_1,n_2,n_3,j}^{eq} = n_1 \mathbf{a}_1 + n_2 \mathbf{a}_2 + n_3 \mathbf{a}_3 + \tilde{\mathbf{R}}_j$ Indices:  $j = 1, \dots, \nu$  atoms in unit cell  $\alpha, \beta = x, y, z$  Cartesian components  $(n_1, n_2, n_3) \equiv \mathbf{n}$ 



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Potential energy @ small displacements:  $\mathbf{R}_{\mathbf{n},j} = \mathbf{R}_{\mathbf{n},j}^{eq} + \mathbf{u}_{\mathbf{n},j}$ 

$$W(\{\mathbf{R}\}) = W(\{\mathbf{R}^{\mathrm{eq}}\}) + \frac{1}{2} \sum_{\mathbf{n},\mathbf{n}'} \sum_{j,j',\alpha,\beta} K_{\alpha\beta}^{jj'}(\mathbf{n} - \mathbf{n}') u_{\mathbf{n}j\alpha} u_{\mathbf{n}'j'\beta} + O(u^3)$$

pairwise interactions:  $K = \frac{\partial^2 W}{\partial \mathbf{R} \partial \mathbf{R}}$ equivalent to springs between atoms

Equations of motion:

$$M_j \frac{d^2 u_{\mathbf{n}j\alpha}}{dt^2} = \sum_{\mathbf{n}'j'} K_{\alpha\beta}^{jj'}(\mathbf{n} - \mathbf{n}') u_{\mathbf{n}'j'\beta}$$

Eigenvalue problem to find  $\mathbf{Q}_j$ :

$$\omega^2 Q_{j\alpha} = \sum_{j'\beta} D^{jj'}_{\alpha\beta}(\mathbf{q}) \, Q_{j'\beta}$$

Plane wave solutions:

$$\mathbf{u}_{\mathbf{n}j} = \frac{\mathbf{Q}_j}{\sqrt{M}_j} e^{i\mathbf{q}\mathbf{R}_{\mathbf{n}j} - i\omega t}$$

Dynamical matrix  $(3\nu \times 3\nu)$  $D_{\alpha\beta}^{jj'}(\mathbf{q}) \equiv \sum_{\mathbf{n}} \frac{K_{\alpha\beta}^{jj'}(\mathbf{n})}{\sqrt{M_j M_{j'}}} e^{-i\mathbf{q}\mathbf{R}_{\mathbf{n}j}}$ 

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Distinct solutions only for **q** in the 1st Brillouin zone For each **q**,  $3\nu$  eigenvectors  $\mathbf{Q}_{j}^{\lambda}(\mathbf{q})$  $3\nu$  eigenvalues  $\omega_{\lambda,\mathbf{q}}^{2}$   $\lambda = 1, \dots, 3\nu$ 

Estimate: 
$$\hbar\omega_{\rm ph} \sim \hbar\sqrt{\frac{K}{M}}, \quad K \sim \frac{E_{\rm el}}{a^2}, \quad E_{\rm el} \sim \frac{\hbar^2}{ma^2} \sim 10 \, {\rm eV}$$

 $\hbar\omega_{\rm ph} \sim \sqrt{\frac{m}{M}} E_{\rm el} \sim 30 \,\mathrm{meV} = 350 \,\mathrm{K}$ 

(1 eV = 11605 K)

### Example: diamond crystal structure



elementary translations face-centered cubic lattice

Phonon dispersion of diamond

 $2\pi\hbar \times 40 \text{ THz} = 165 \text{ meV}$ 



P. Yu and M. Cardona, "Fundamentals of semiconductors"

### Optical probe: infrared spectroscopy



#### Photon absorption:

momentum conservation  $q = -\frac{\omega}{c}$ energy conservation  $\omega = \omega$ 

$$=rac{\omega}{c}\sin heta$$
 very small  $=\omega_{q,\lambda}$ 

Bulk MoS<sub>2</sub> from PRB 3, 4286 (1971)



Polarizability  $\alpha(\omega) = \text{const} + \frac{A}{\omega - \omega_{\lambda} + i\Gamma_{\lambda}/2}$ 

- measure absorption or reflectivity

$$2\pi\hbar c \times 400 \,\mathrm{cm}^{-1} = 50 \,\mathrm{meV}$$

### **Optical probe: Raman spectroscopy**

incident scattered photon  $\omega_i \quad \theta_s \quad \omega_s$  photon

 $\omega_{\rm s} < \omega_{\rm i} - {\rm Stokes} (T = 0)$ 

 $\omega_s > \omega_i$  – anti-Stokes (thermal phonon population)

Energy-momentum conservation for *n*-phonon Stokes:  $\mathbf{q}_1 + \ldots + \mathbf{q}_n = "0"$  $\omega_{\mathbf{q}_1\lambda_1} + \ldots + \omega_{\mathbf{q}_n\lambda_n} = \omega_{\mathbf{i}} - \omega_{\mathbf{s}}$ 



Raman spectrum of monolayer MoS<sub>2</sub> Zhang *et al*, Chem Soc. Rev. **44**, 2757 (2015)

## Acoustic phonons

Crystal: continuous translation symmetry spontaneously broken





 $W({\mathbf{R}})$  invariant under a constant shift

$$\mathbf{R}_{\mathbf{n}j} \mapsto \mathbf{R}_{\mathbf{n}j} + \mathbf{u} \quad \Longrightarrow \quad \sum_{j,j'} D_{\alpha\beta}^{jj'}(\mathbf{q} \to 0) = \frac{\mathcal{D}_{\alpha\beta\alpha'\beta'} q_{\alpha'}q_{\beta'}}{\operatorname{symmetric} 4\operatorname{-rank tensor}}$$

Sufficiently high crystal symmetry (tetrahedral, cubic)

$$\mathcal{D}_{\alpha\beta\alpha'\beta'} = \mathcal{A}\,\delta_{\alpha\beta}\delta_{\alpha'\beta'} + \mathcal{B}\,(\delta_{\alpha\alpha'}\delta_{\beta\beta'} + \delta_{\alpha\beta'}\delta_{\alpha'\beta})$$

Transverse and longitudinal sound velocity 
$$v_{\rm L} > v_{\rm T} \sqrt{2}$$

$$\sum_{j,j'} D_{\alpha\beta}^{jj'}(\mathbf{q}) = \mathcal{A} \,\delta_{\alpha\beta} q^2 + 2\mathcal{B} \,q_\alpha q_\beta$$
$$= \mathcal{A} \left( \delta_{\alpha\beta} q^2 - q_\alpha q_\beta \right) + \left( \mathcal{A} + 2\mathcal{B} \right) q_\alpha q_\beta$$
$$\equiv v_{\mathrm{T}}^2 \left( \delta_{\alpha\beta} q^2 - q_\alpha q_\beta \right) + v_{\mathrm{L}}^2 \,q_\alpha q_\beta$$

## Acoustic phonons



soft Goldstone modes



 $W({\mathbf{R}})$  invariant under a constant shift

$$\mathbf{R}_{\mathbf{n}j} \mapsto \mathbf{R}_{\mathbf{n}j} + \mathbf{u} \quad \Longrightarrow \quad \sum_{j,j'} D_{\alpha\beta}^{jj'}(\mathbf{q} \to 0) = \frac{\mathcal{D}_{\alpha\beta\alpha'\beta'} q_{\alpha'}q_{\beta'}}{\operatorname{symmetric} \operatorname{4-rank \ tensor}} O(q^4)$$

Sufficiently high crystal symmetry (tetrahedral, cubic)

Transverse and longitudinal sound velocity  $v_{\rm L} > v_{\rm T} \sqrt{2}$ 

 $30 \mathrm{meV} \times 1 \mathrm{\AA}/\hbar \sim 5 \mathrm{km/s}$ 

aluminium: 6.4, 3.0 km/s copper: 4.8, 2.3 km/s silicon: 8.4, 5.8 km/s

# Phonon imaging



FIG. 11. (a) Ballistic phonon image with laser beam obliquely incident on three sample faces. The bolometer is in the center of the back left (001) face. (b) Calculated J=0 singularities projected onto an equivalent cube.

D. M. Basko, "Phonons" @ DRTBT 2024

## Phonon kinetics in insulators

# Phonon specific heat



Potential energy expanded in small displacements:

$$W(\{\mathbf{R}\}) = W(\{\mathbf{R}^{\mathrm{eq}}\}) + \frac{1}{2} \sum_{\mathbf{n},\mathbf{n}'} \sum_{j,j',\alpha,\beta} K_{\alpha\beta}^{jj'}(\mathbf{n} - \mathbf{n}') u_{\mathbf{n}j\alpha} u_{\mathbf{n}'j'\beta} + O(u^3)$$

Potential energy expanded in small displacements:

$$W(\{\mathbf{R}\}) = W(\{\mathbf{R}^{eq}\}) + \frac{1}{2} \sum_{\mathbf{n},\mathbf{n}'} \sum_{j,j',\alpha,\beta} K_{\alpha\beta}^{jj'}(\mathbf{n} - \mathbf{n}') u_{\mathbf{n}j\alpha} u_{\mathbf{n}'j'\beta} + \frac{1}{6} \sum \Lambda_{\alpha_1\alpha_2\alpha_3}^{j_1j_2j_3}(\mathbf{n}_1, \mathbf{n}_2, \mathbf{n}_3) u_{\mathbf{n}_1j_1\alpha_1} u_{\mathbf{n}_2j_2\alpha_2} u_{\mathbf{n}_3j_3\alpha_3} + O(u^4)$$

$$\Lambda \sim \frac{E_{\rm el}}{a^3} \sim 10 \; {\rm eV/\AA}^3$$

Potential energy expanded in small displacements:

$$W(\{\mathbf{R}\}) = W(\{\mathbf{R}^{eq}\}) + \frac{1}{2} \sum_{\mathbf{n},\mathbf{n}'} \sum_{j,j',\alpha,\beta} K_{\alpha\beta}^{jj'}(\mathbf{n} - \mathbf{n}') u_{\mathbf{n}j\alpha} u_{\mathbf{n}'j'\beta} + \frac{1}{6} \sum \Lambda_{\alpha_1\alpha_2\alpha_3}^{j_1j_2j_3}(\mathbf{n}_1, \mathbf{n}_2, \mathbf{n}_3) u_{\mathbf{n}_1j_1\alpha_1} u_{\mathbf{n}_2j_2\alpha_2} u_{\mathbf{n}_3j_3\alpha_3} + O(u^4)$$

$$\Lambda \sim \frac{E_{\rm el}}{a^3} \sim 10 \, {\rm eV/\AA}^3$$

#### Third-order processes:



(umklapp scattering)



Figure 1 The splitting of an LO phonon into two acoustic phonons and subsequent decay into lower-frequency phonons. The dispersion curves are for GaAs. (from J. P. Wolfe, "Imaging Phonons")

uncertainty principle **ok** 

 $\mathbf{q}_1$ 

q

# Anharmonicity and phonon decay

Low energy, low temperature: acoustic phonons, no umklapps

 $v_{\rm T}|{\bf q}_1 + {\bf q}_2| = v_{\rm T}|{\bf q}_1| + v_{\rm T}|{\bf q}_2|$  impossible (triangle inequality +  $\omega_{{\bf q},{\rm T}}$  concave function)

Transverse acoustic phonons do not decay

$$v_{\rm L}|\mathbf{q}_1 + \mathbf{q}_2| = v_{\rm T}|\mathbf{q}_1| + v_{\rm T}|\mathbf{q}_2|$$
 possible, but  $\frac{1}{\tau} \sim \omega_D \frac{\hbar\omega_D}{Ka^2} \left(\frac{\omega}{\omega_D}\right)^5$ 



 $\mathbf{q}_2$ 

Yu & Cardona, "Fundamentals of semiconductors"

LA phonon lifetime in silicon:FrequencyLifetime $\nu$  (THz) $\tau_a$  (ns)7.50.00063.750.0181.880.580.9419

(from J. P. Wolfe, "Imaging Phonons")

Goldstone modes are robust

# Thermal conductivity

$$\frac{\partial \mathcal{E}(T)}{\partial t} = -\boldsymbol{\nabla} \cdot \mathbf{J} \quad \text{heat current density}$$

 $\mathbf{J} = -\kappa(T) \, \nabla T$  Fourier's law (the current must vanish @ T = const)



 $rac{\kappa}{C_v} \sim D \sim rac{l^2}{\tau} = v^2 \, au$  phonon diffusion coefficient l = v au mean free path

$$\kappa(T) \sim C_v(T) v^2 \tau(T)$$

# **Thermal conductivity**

<u>High temperatures</u>  $T \gg \Theta_D$ :  $\kappa \sim \frac{1}{a^3} \frac{v^2}{\omega_D} \frac{Ka^2}{T} \sim \frac{Ka}{\hbar} \frac{\Theta_D}{T}$  (Debye, 1929)

**Low temperatures**  $T \ll \Theta_D$ : 1. TA phonons  $\tau = \infty$ 2. LA phonons  $\tau \propto 1/\omega^5$ , but  $\mathbf{q} = \mathbf{q}_1 + \mathbf{q}_2 + \mathbf{b}$  no umklapps momentum is conserved energy current does not relax

A high-energy phonon needed to provide umklapp  $\implies \kappa \propto e^{\Theta_D/T}$  (Peierls, 1929)

Phonon scattering on isotopic defects: 
$$\frac{1}{\tau} \sim \omega_D \frac{n_d}{n_0} \left(\frac{\Delta M}{M}\right)^2 \left(\frac{\omega}{\omega_D}\right)^4$$
 (Pomeranchuk, 1942) fraction of defective atoms

All phonon scattering mechanisms become very inefficient at low temperatures

## **Ballistic phonons**



Diffuse mismatch model:

Acoustic mismatch model: wave refraction at a flat interface random scattering at a rough interface

#### Isotope and boundary effects



FIG. 4. Thermal conductivity of LiF showing the effect of isotopes. % 'Li in LiF: (A) 99.99, (B) 97.2, (C) 92.6 (natural LiF), (D) 50.8. Mean crystal widths: (A) 7.25 mm, (B) 5.33 mm, (C) 5.44 mm, (D) 5.03 mm. Crystals A, B, and C were regrown

P. D. Thacher, Phys. Rev. **159**, 975 (1967)



FIG. 1. Thermal conductivity of isotopically pure LiF showing the effect of boundaries for sandblasted crystals. Mean crystal widths: (A) 7.25 mm, (B) 4.00 mm, (C) 2.14 mm, (D) 1.06 mm.

### Isotope and boundary effects



FIG. 5. Thermal conductivity of a pure silicon single crystal with different surface treatments. Top curve: Syton polished and cleaned; bottom: sandblasted. The intermediate curves were measured after metal films were deposited (*ex situ*) onto the polished and cleaned surfaces.

Klitsner & Pohl Phys. Rev. B **36**, 6551 (1987) D. M. Basko, "Phonons" @ DRTBT 2024

## Phonon kinetics in metals



#### **Uniform system is electroneutral**

Deformed system with ion displacements:  $\mathbf{u}_n = \mathbf{u}(\mathbf{R}_n) = \mathbf{u}_{\mathbf{q}}e^{i\mathbf{q}\mathbf{R}_n - i\omega t}$ change in the ionic density  $\frac{\delta n_i(\mathbf{R})}{n_i} = -\nabla \cdot \mathbf{u}(\mathbf{R}) = -i\mathbf{q}\mathbf{u}_{\mathbf{q}} e^{i\mathbf{q}\mathbf{R} - i\omega t}$ Coulomb potential  $\varphi(\mathbf{R}) = \int \frac{d^3\mathbf{R}'}{|\mathbf{R} - \mathbf{R}'|} Ze \,\delta n_i(\mathbf{R}') = -\frac{4\pi Zen_i}{q^2} i\mathbf{q}\mathbf{u}_{\mathbf{q}} e^{i\mathbf{q}\mathbf{R} - i\omega t}$ 

$$\omega^2 = \frac{4\pi n_{\rm i}(Ze)^2}{M} \sim \omega_D^2$$

ionic plasma frequency, not acoustic phonon

# Screening by the Fermi sea



Self-consistent potential from ions and electrons: screened Coulomb

$$-\nabla^2 \varphi(\mathbf{r}) = 4\pi Z e \,\delta n_{\rm i}(\mathbf{r}) - 4\pi e \,\delta n_{\rm e}(\mathbf{r}) \implies \varphi(\mathbf{R}) = \int \frac{d^3 \mathbf{R}' \, e^{-\kappa_D |\mathbf{R} - \mathbf{R}'|}}{|\mathbf{R} - \mathbf{R}'|} \, Z e \,\delta n_{\rm i}(\mathbf{R}')$$

$$\kappa_D \equiv \sqrt{4\pi e^2 \nu} \sim 1 \text{ \AA}^{-1}$$
 inverse Debye (Thomas-Fermi) screening length



#### **Uniform system is electroneutral**

Deformed system with ion displacements:  $\mathbf{u}_n = \mathbf{u}(\mathbf{R}_n) = \mathbf{u}_{\mathbf{q}}e^{i\mathbf{q}\mathbf{R}_n - i\omega t}$ change in the ionic density  $\frac{\delta n_i(\mathbf{R})}{n_i} = -\nabla \cdot \mathbf{u}(\mathbf{R}) = -i\mathbf{q}\mathbf{u}_{\mathbf{q}} e^{i\mathbf{q}\mathbf{R} - i\omega t}$ Screeneed Coulomb potential  $\varphi(\mathbf{R}) = -\frac{4\pi Z e n_i}{q^2 + \kappa_D^2} i\mathbf{q}\mathbf{u}_{\mathbf{q}} e^{i\mathbf{q}\mathbf{R} - i\omega t}$  $\omega^2 = \frac{4\pi n_i(Ze)^2}{M} \frac{q^2}{\chi^2 + \kappa_D^2} \approx v_L^2 q^2$   $v_L = \sqrt{\frac{Z^2 \rho}{M^2 \nu}} \sim (\text{a few}) \frac{\mathrm{km}}{\mathrm{s}}$ 

# **Electron-phonon interaction**

#### **Born-Oppenheimer:**

 $W({\mathbf{u}_n})$  from electronic ground state energy at fixed  ${\mathbf{u}_n}$ 

$$M \frac{d^2 \mathbf{u}_n}{dt^2} = -\frac{\partial W}{\partial \mathbf{u}_n} \quad \text{basic assumption:} \\ \text{electrons follow adiabatically the nuclear motion}$$

Validity:  $\omega \ll E_1 - E_0$  electronic energy gap

Breaks down in any metal, semimetal, doped semiconductor



# Phonon absorption by electrons

Electronic density response to an oscillating potential from the Kubo formula:  $\Pi(\mathbf{q}, \omega)$  Phonon decay rate:

$$\frac{1}{\tau} = -\omega \operatorname{Im} \Pi(\mathbf{q}, \omega) \, \frac{n_{\rm i} Z^4 / \nu^2}{2M v_L^2} \sim \omega \sqrt{\frac{m}{M}}$$

The main mechanism of acoustic phonon decay in metals: **phonon absorption by electrons** 

or escape to the substrate (Kapitza)

Decay rate due to anharmonicity:

$$rac{1}{ au}\sim\omega_D\,\sqrt{rac{m}{M}}iggl(rac{\omega}{\omega_D}iggr)^5$$
 m

much weaker

# Phonon absorption by electrons

Electronic density response to an oscillating potential from the Kubo formula:  $\Pi(\mathbf{q}, \omega)$  Phonon decay rate:

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ch aker

#### **Inverse process: phonon emission by electrons** (detailed balance)

Electron temperature  $T_{el}$ Phonon temperature  $T_{ph}$  $(T_{\rm el}, T_{\rm ph} \ll \Theta_D)$ 



Heat flow from electrons to phonons: power per unit volume =  $\sum (T_{el}^5 - T_{ph}^5)$ experimentally measurable coefficient  $\int_0^\infty q^2 dq \, \frac{\hbar v q}{e^{\hbar v q/T} - 1} \, \frac{1}{\tau} \propto T^5$ 

# Phonon absorption by electrons

Wellstood, Urbina & Clarke, PRB **49**, 5942 (1994)





FIG. 8. Measured electron temperature  $T_e$  vs dissipated power for resistor 1 at two bath temperatures. The solid line is the fit of Eq. (4.1) to 25-mK data with n = 4.87. The dashed line is the "simple heating model."

Electron temperature  $T_{el}$ Phonon temperature  $T_{ph}$ 



#### Heat flow from electrons to phonons:

power per unit volume =  $\sum (T_{el}^5 - T_{ph}^5)$ experimentally measurable coefficient  $\int_0^\infty q^2 dq \, \frac{\hbar v q}{e^{\hbar v q/T} - 1} \frac{1}{\tau} \propto T^5$ 

### Specific heat and thermal conductivity

Phonons: 
$$C_{\rm ph}(T \ll \Theta_D) \sim \frac{(T/\Theta_D)^3}{a^3}$$
  $C_{\rm ph}(T \gg \Theta_D) \sim \frac{1}{a^3}$   
Electrons:  $C_{\rm el}(T) = \frac{\partial}{\partial T} 2 \int \frac{d^3 \mathbf{p}}{(2\pi\hbar)^3} \frac{\epsilon_{\mathbf{p}}}{e^{(\epsilon_{\mathbf{p}} - \epsilon_F)/T} + 1}$   
 $C_{\rm el}(T \ll \epsilon_F) = \frac{\pi^2}{3} \nu T \sim \frac{T/\epsilon_F}{a^3}$  dominate below a few Kelvins



Superconductor: 
$$C_{\rm el}(T \ll T_c) = \sqrt{2\pi} \nu \Delta \left(\frac{\Delta}{T}\right)^{3/2} e^{-\Delta/T}$$

### Specific heat and thermal conductivity

Phonons: 
$$C_{\rm ph}(T \ll \Theta_D) = \frac{2\pi^2}{15} \left( \frac{T^3}{(\hbar v_{\rm L})^3} + \frac{2T^3}{(\hbar v_{\rm T})^3} \right)$$
  
Electrons:  $C_{\rm el}(T \ll \epsilon_F) = \frac{\pi^2}{3} \nu T$  dominate below a few Kelvins

Electronic thermal conductivity:  $\kappa_{el} \sim C_{el} v_F^2 \tau_{el}$  dominates over phonons much larger than sound velocity Electric conductivity:  $\sigma \sim e^2 \nu v_F^2 \tau_{el}$ 

Wiedemann-Franz law: 
$$\frac{\kappa}{\sigma} = \frac{\pi^2}{3} \frac{T}{e^2}$$

# **Electron energy relaxation**



<u>Superconductors</u>: quasiparticle gap  $\Delta$ breaking a Cooper pair: cost  $2\Delta$ 



# **Electron energy relaxation**



# Electron energy relaxation



, slopes between 3 and 4 clean electrons:  $1/ au_{
m el} \propto T^3$ 

electrons scattering on impurities:  $\frac{1}{\tau_{\rm el}} \propto T^4$ 

M. Sidorova *et al.*, PRB **102**, 054501 (2020)

**Disordered NbN** 

D. M. Basko, "Phonons" @ DRTBT 2024

## Relaxation cascade in a detector

# **Overall picture**



FIG. 1. Schematic picture of photoelectron energy down-conversion in a superconductor.

# Formation of the phonon bubble



## Phonon down-conversion







# **Quasiparticle cloud**



#### **Detect quasiparticle population:**

- 1. Increase in the kinetic inductance
- 2. Increase in the dissipative conductivity

Cloud expansion: quasiparticle diffusion

# Useful textbooks

Ashcroft and Mermin, Solid State Physics

Ziman, Electrons and Phonons: The Theory of Transport Phenomena in Solids

Lifshitz & Pitaevskii, Physical Kinetics

Abrikosov, Fundamentals of the Theory of Metals

Yu & Cardona, Fundamentals of Semiconductors

Wolfe, Imaging Phonons: Acoustic Wave Propagation in Solids